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INFORMATION DISCLOSURE CITATION  (Use several sheets if necessary)		Applicant Kozlowski, Lester J., et al.	
		Filing Date September 29, 2000	Group 2612

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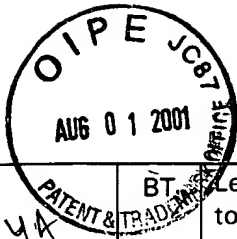
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Examiner <i>Y. Schubert</i>		Date Considered 06/08/04
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		

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